## On the stability of hole crystals in layered cuprates.

G.Rastelli<sup>1</sup>, S.Fratini<sup>2</sup>, and P.Quemerais

Istituto Nazionale di Fisica della Materia and Dipartin ento di Fisica, Universita dell'Aquila, via Vetoio, I-67010 Coppito-L'Aquila, Italy Laboratoire d'Etudes des Proprietes Electroniques des Solides, CNRS

BP166 - 25, A venue des Martyrs, F-38042 G renoble Cedex 9, France

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Abstract. Recent STM measurements have revealed the existence of periodic charge modulations at the surface of certain cuprate superconductors. Here we show that the observed patterns are compatible with the form ation of a three-dimensional crystal of doped holes, with space correlations extending between di erent Cu-O layers. This puts severe constraints on the dynam ical stability of the crystallised hole structure, resulting in a close relationship between the periodicity of the electronic modulation and the interlayer distance.

PACS. 74.72 -h Cuprate superconductors (high-T c and insulating parent com pounds) { 71.30 + h M etalinsulator transitions and other electronic transitions { 71.38.k Polarons and electron-phonon interactions

Since the discovery of high tem perature superconductivity, several m icroscopic m odels have been proposed in order to explain the com plex phase diagram of the cuprates. 1 In particular, the presence of an antiferrom agnetic phase in the parent compounds has led to a huge theoretical e ort on models with local electronic interactions, such as the Hubbard or t-J m odels. It is seldom realised that, when few carriers are added to an insulating system by doping, the long range part of the Coulomb repulsion is not screened, and can not be neglected a priori.

Interest in the long range interactions has been recently revived by the observation, by scanning tunneling m icroscopy, of periodic m odulations of the electronic density of states at the surface of the cuprate com pounds (Na-CCOC). [9] A lthough som e of the features have been interpreted in terms of quasiparticle interference e ects, the emergence of modulations with a dispersionless ordering vector q ' 2 =4 $a_0$  directed along the Cu-O bonds, strongly points to the existence of an underlying charge order, characteristic of the less conducting (pseudogap) regions. Am ong other possibilities, the latter could be ascribed to the form ation of a W igner crystal [10] of holes [9,11,12,13,14,15] an insulating ordered state arising in electronic systems at low density, when the long-range Coulom b interactions are dom inant | or to the ordering ofhole pairs. [16,17,18,19]

The aim of this work is to determ ine if the concept of hole crystallisation is compatible with the experimental observations in the cuprates. It is clear that a complete m icroscopic treatment of the problem should consider, in addition to the aforem entioned long range Coulomb repulsion, also the interaction of the doped holes with all the degrees of freedom of the host material, including the x localised electrons in the M ott insulator, the ions of the host lattice, chem ical in purities, etc... Instead of attempting this form idable task, or choosing to rely on a de nite microscopic model, we shall approach the problem starting from the experim ental observation that the holes are localised in an ordered pattern, and describe the system in the fram ework of a phenom enological Lorentz model. As we will show, a great insight into the problem can be gained already at this phenom enological level, leading to precise constraints on the admissible shape and periodicity of the charge ordering patterns.

Let us consider the holes to be located at the sites R  $_{\rm i}$ Bi<sub>2</sub>Sr<sub>2</sub>CaCu<sub>2</sub>O<sub>8+</sub> (Bi-2212) [1,2,3,4,5,6,7,8] and Ca<sub>2x</sub>Na<sub>x</sub> of the three dimensional Bravais lattice. This is a sensible assumption because, despite the structural constraints in the cuprates, which con ne the carrier motion into Cu-O layers, the long range C oulom b interactions are isotropic, so that the ordering within a Cu-O layer is certainly affected by the positions of the holes on di erent layers. A llowing for small (inplane) displacements  $R_i ! R_i + u_i$ around the equilibrium positions leads to the following quadratic H am iltonian:

$$H_{I} = \sum_{i}^{X} H_{i} + \frac{1}{2_{1}} \sum_{i \in j}^{X} u_{i} I_{ij} u_{j} + \sum_{i}^{X} \frac{1}{2} m !_{0}^{2} u_{i}^{2}:$$
(1)

The rst term on the right represents all the static longrange C oulom b interaction e ects, including the M adelung energy of the Bravais lattice, plus the restoring potentials acting at each R i, due to the repulsion of the other holes localised at R i & R i. The second term is the usual



F ig. 1. The anisotropic crystal structures considered in the text: a) single layer com pounds (d is the interlayer spacing, a is the hole-hole distance within a layer); b) bilayer com pounds (l is the distance between neighbouring layers).

dipole-dipole interaction arising between particle oscillations. The indices ; = x; y are summed, and  $I_{ij} = \frac{\Re_{ij}\hat{f}}{\Re_{ij}\hat{f}}$ . It should be noted that the terms  $H_i$  are screened by the static dielectric constant  $_s$  of the host medium, while the dipolar interactions between fast hole oscillations are ruled by the high frequency dielectric constant  $_1$ . This discrepancy can have in portant consequences in the cuprates, where  $_s$  is substantially larger than  $_1$  owing to the ionic polarisability. The last term represents the (unknown) potential which, within our phenom enological approach, accounts for the in uence of the host m aterial on the dynam ics of the individual holes (interaction with the magnetic, ionic degrees of freedom ...).

Let us rst consider a \pure" W igner crystal, which is obtained by setting  $!_0 = 0$  in the above H am iltonian. [20] Am ong the di erent three-dimensional B ravais lattices compatible with the structural anisotropy im posed by the Cu-O layers, we shall deliberately restrict ourselves to the cases which present a square charge ordering within the planes, as observed in experiments.W ithin this subclass, it can be demonstrated that the body centered tetragonal (BCT), illustrated in Fig. 1*a.*, has the lowest M adelung energy.

To determ ine if such an isotropic W igner crystal is stable, we now evaluate the frequencies  $!_k \ ($  = branch index) of the corresponding collective charge density os-



Fig. 2. Spectrum of the collective excitations of di erent W igner crystals, for wavevectors k within the plane. Left panel: the usual body centered cubic (BCC) W igner lattice ( = 1). Center panel: anisotropic BCT lattice with = 0.5, which is unstable against shear, as signaled by the existence of purely imaginary solutions with  $\frac{1}{k}$  < 0. R ight panel: the same anisotropic lattice embedded in a polarisable medium with =  $\frac{1}{p} = 4$  ne<sup>2</sup> m  $\frac{1}{r}$ , m being the hole mass, and n the hole density. The symmetry points indicated in the graphs are de ned as follows, in units of =a. Left panel: = (0;0), H = (2;0), N = (1;1). Centre and right panel: = (0;0), N = (1 + <sup>2</sup>;0) X<sup>0</sup> = (1 + <sup>2</sup>;1 <sup>2</sup>), X = (1;1).

cillations. The calculation is performed using standard Ewald summation techniques, at dienent values of the anisotropy ratio = a=2d (a being the inplane interparticle spacing, determined by the hole concentration, and d the interlayer distance). The excitation spectra are reported in gure 2. In the isotropic case (= 1, left panel), we recover the body centered cubic (BCC) structure, which is known to be mechanically stable. Generic BCT crystals are also stable for weak anisotropy ratios within the range 0.66 < 1:07. Note that this identies an interval of hole concentrations, where a square ordering in the planes arises naturally due to the three-dimensional character of the C oulom b interactions.

For anisotropy ratios outside the range 0.66 < < 1.07, the em ergence of in aginary eigenfrequencies (! $\frac{2}{k} < 0$ , see g.2, central panel) signals that the BCT structure considered here is, in principle, mechanically unstable, so that the preferred W igner crystal structure has a di erent symmetry. However, energetic di erences between competing structures are expected to be very sm all, since M adelung energies are essentially determined by long range e ects. Therefore, it is likely that the observed hole distributions are in uenced by other microscopic mecha-



F ig. 3. The characteristic energy scale of the trapping potential necessary to stabilise an anisotropic hole crystal, as a function of the anisotropy ratio . Full lines corresond to the single layer host structure of Na-CCOC, with d = 7:75A and  $_1 = 4.5$ , at di erent values of the polarisability ratio (from left to right, = 1;0:8;0:5;0:17). The dashed line is for the bilayer structure of Bi-2212, with  $_1 = 4.9$  and = 0.5. The system becomes increasingly unstable upon increasing the hole concentration (i.e. reducing ). The di erent periodicities observed in Na-CCOC and in Bi-2212 (indicated by arrows) correspond to a common localisation energy 0:16eV, characteristic of the host cuprate materials.

nism s, such as the commensurability with the Cu-O host lattice, which justi es our restriction to square planar orderings. [21]

Let us now consider a crystal of holes embedded in a polarisable m edium. In this case, an additional source of instability appears, causing an overall downward shift of the excitation spectrum (g.2, right panel). This occurs because, owing to the ionic polarisability (i.e. as soon as = 1 = s < 1), the static restoring potentials that b-calise the holes, and their mutual dipolar interactions, responsible for the dispersion of the collective frequencies, are screened by di erent dielectric constants. We conclude that some additional localising mechanism is required to stabilize a hole crystal in polarisable media such as the cuprates, and turn our attention to the full Lorentz m odel of eq. (1). The collective frequencies k in this case can be derived straightforwardly from the solution of the pure C oulom b problem as: [20]

$${}^{2}_{k} = !{}^{2}_{k} + !{}^{2}_{0}$$
: (2)

M echanical stability requires that the eigenfrequencies  $_{\rm k}$  are all real. This, according to equation (2), sets a lower bound on the energy scale of the localising potential:  $|{}^2_0$   $|{}^2_{\rm m}$  in, where  $|{}^2_{\rm m}$  is de ned as the modulus of the most negative eigenvalue  $|{}^2_{\rm k}$  over the B rillouin zone. This quantity is reported in gure 3 as a function of , for di erent values of the polarisability ratio . We see that it is low and at at large (i.e. at low hole concentrations), but it rises sharply for < 0.5, indicating that charge patterns whose inplane periodicity is much shorter than the interlayer distance are very unlikely to occur, since these can only be stabilised by invoking an additional localisa-

tion mechanism with a very large energy scale. This general observation establishes a direct link between the admissible periodicity of the charge modulations | an electronic property| and the distance between Cu-O layers | a structural constraint. To be more speci c, using the appropriate values d = 7:75A,  $a_0 = 3.85A$ ,  $_1 = 4.5$  and

0.5 [22] for Na-CCOC, it can be read directly from gure 2 that the observed periodicity  $a = 4a_0$  ( = 1) im – plies that the characteristic energy scale involved in the localisation of the holes is (at least) !<sub>0</sub> 0:16eV.

If the proposed picture is correct, it should apply to other cuprates, such as the bism uth based B  $i_2$  Sr<sub>2</sub>C aC u<sub>2</sub>O  $_{8+}$  . These compounds present an additional constraint related to the bilayer structure, for which the corresponding low est energy con guration is illustrated in g1b.As in the single layer case, the calculated excitation spectrum shows that a pure W igner crystal of holes is unstable due to the ionic polarisability, and an additional source of localisation must be considered. Repeating the same arguments as in Na-CCOC, with parameters d = 15:5A, l = 3Aand dielectric constants  $_1 = 4:9$ , 0:5,[23] we read qure 3 (dashed line) that the observed periodicifrom ties  $a=a_0 = 4:3$  4:7 [1,4,6,7,8] ( = 0:53 0:58) are stabilised by taking  $!_0 = 0.15$  0.17eV, which is remarkably close to the value obtained in Na-CCOC. This result strongly points to the existence of a common localisation mechanism, which could be at the origin of the di erent periodicities observed in di erent com pounds. Following the same steps in the case of the single layer compound Bi<sub>2</sub>Sr<sub>2</sub>CuO<sub>6</sub>, which has a shorter interlayer distance than Na-CCOC (d = 12:3A), we predict a crystal periodicity a=a₀ 3:4 that would be interesting to verify experim entally.

Before enquiring about itsm icroscopic foundations, let us analyse the consequences of the present scenario. First of all, since ! 0 re ects the interaction of individual holes with the host material, in principle it should not depend much on the doping level. Here we take it as a constant, characteristic of the parent cuprate com pounds. A coording to equation (2), in the limit of vanishing hole density, where all the  $!_k$  ! 0, the excitation spectrum will be dominated by ! ... Upon increasing the hole concentration, however, the collective frequencies spread away from  $!_0$  due to the term  $!_k^2$  , which adm its both positive and negative values. As a consequence, the longitudinal charge oscillations get hardened upon doping, while transverse oscillations are progressively softened, until a given eigenfrequency  $k = k_c$  vanishes, leading to a polarisation catastrophe at a critical concentration  $x_c$ . [13,20,24,25] The predicted softening of long wavelength transverse oscillations, [13,25] which is entirely due to the long-range polarisability of the m edium, has been experim entally observed in system atic studies of the optical conductivity spectra of both electron- and hole-doped cuprates in the underdoped region. [26,27] Sim ilar signatures of the polarisation catastrophe can be expected in spectroscopic ellipsom etry and electron energy loss spectroscopy.

In the foregoing discussion, we have assumed that all of the doped holes are crystallised, so that the system is

insulating for  $x < x_c$ . In this case, the periodicity of the m odulation varies continuously with x until it reaches its lim iting value  $a=a_0 = (n_1=x_c)^{1=2}$  at the critical concentration  $(n_1 = 1; 2 \text{ for single and bilayer host structures})$ . [28] W hen further holes are doped into the system beyond  $x_c$ , these can not be accom odated in the crystallised state, which is at the border of an instability. If, as indicated by experiments, the hole crystal survives for  $x > x_c$ , one possibility is that the excess holes settle in the interstitials of the main ordering pattern, creating a superim posed modulation, as observed in the Na-CCOC samples. [9] A nother possibility is that the system phase separates into insulating (crystallised) and conducting regions, as seems to be the case in Bi-2212.[7] The question of crystal stability in the presence of additional mobile charges, and the consequent screening of the long range interactions, remains open.

Based on the emerging scenario, we can now speculate on the microscopic mechanism underlying the localisation of the holes. First of all, the energy scale  $!_0$  identi ed above is de nitely too large to be imputed exclusively to the binding potentials of chem ical impurities, or to the pinning by commensurability e ects. [29] On the other hand, the interaction with the antiferrom agnetic background, which is ruled by typical exchange energies 0:1eV, would constitute a viable possibility. How-J ever, in strongly polarisable m aterials, the excess charges added by doping are expected to form dielectric polarons. Indeed, it can be recognized that the value of  $!_0$  derived in this work coincides with the locus of a well de ned absorption band, ubiquitous in the infrared optical spectra (!) of strongly underdoped cuprates, which is generally ascribed to the form ation of polarons, [30] suggesting that the additional mechanism required to stabilise the hole crystal is the polaron self-trapping potential.[31] The W igner crystallization of polarons in the insulating phase of the cuprates has been proposed independently by Rem ova et al., [11] and Q u em erais. [12] The quantum m elting of such polaron crystalhas been studied in refs. [13,25,32, 33] yielding sim ilar conclusions as in the present paper.

O ur analysis dem onstrates that the periodic m odulations observed at the surface of the cuprates are com patiblew ith the crystallisation of holes, arising due to the com – bined e ects of the long range C oulom b interactions, and of som e additional localising phenom enon, whose characteristic energy scale is  $!_0$  0:16eV. A lthough several m icroscopic m echanism s can be involved, polaron form ation appears as a good candidate to stabilise a hole crystal in the cuprates.

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$$x_{c} = \frac{3_{1}}{16(1)} + \frac{h!_{0}}{Ryd} + \frac{2}{a_{B}^{3}}$$

where  $a_B$  is the Bohr radius and Ryd = 13:6eV. Taking 1 45, 0:5 and !0 0:16eV yields  $x_c = 3:9$ 10 <sup>3</sup> (d= $a_B$ ) which gives  $x_c$  0:05 0:11 for several cuprate crystal structures, with corresponding m odulations  $a=a_0$ 3:5 6.

- 29. A lthough they certainly favor charge ordering, com m ensurability e ects decrease drastically when moving away from simple fractional llings, and it has been shown that they do not dom inate the W igner crystal stability at low concentrations [see e.g. Y. Noda & M. Im ada, Phys. Rev. Lett. 89, 176803 (2002); H.Falakshahi et al., Eur. Phys. J.B 39, 93 (2004)]
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